MPS6717

One Watt Amplifier Transistor

NPN Silicon

Features

• Pb-Free Packages are Available*

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector - Emitter Voltage	V_{CEO}	80	Vdc
Collector - Base Voltage	V _{CBO}	80	Vdc
Emitter – Base Voltage	V _{EBO}	5.0	Vdc
Collector Current – Continuous	I _C	500	mAdc
Total Device Dissipation @ T _A = 25°C Derate above 25°C	P _D	1.0 8.0	W mW/°C
Total Device Dissipation @ T _C = 25°C Derate above 25°C	P _D	2.5 20	W mW/°C
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-55 to +150	°C

THERMAL CHARACTERISTICS

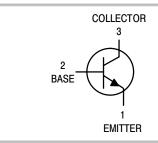
Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	125	°C/W
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	50	°C/W

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.



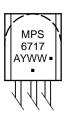
ON Semiconductor®

http://onsemi.com





MARKING DIAGRAM



MPS6717 = Device Code A = Assembly Location

Y = Year
WW = Work Week
Pb-Free Package
(Note: Microdot may be in either location)

ORDERING INFORMATION

Device	Package	Shipping [†]
MPS6717	TO-92	5000 Units / Bulk
MPS6717G	TO-92 (Pb-Free)	5000 Units / Bulk
MPS6717RLRA	TO-92	2000/Tape & Reel
MPS6717RLRAG	TO-92 (Pb-Free)	2000/Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

^{*}For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

MPS6717

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS	·			
Collector – Emitter Breakdown Voltage (Note 1) $(I_C = 1.0 \text{ mAdc}, I_B = 0)$	V _(BR) CEO	80	_	Vdc
Collector – Base Breakdown Voltage $(I_C = 100 \mu Adc, I_E = 0)$	V _{(BR)CBO}	80	-	Vdc
Emitter – Base Breakdown Voltage ($I_E = 10 \mu Adc, I_C = 0$)	V _{(BR)EBO}	5.0	_	Vdc
Collector Cutoff Current (V _{CB} = 60 Vdc, I _E = 0)	I _{CBO}	_	0.1	μAdc
Emitter Cutoff Current (V _{EB} = 5.0 Vdc, I _C = 0)	I _{EBO}	_	10	μAdc
ON CHARACTERISTICS	·			
DC Current Gain $ \begin{aligned} \text{(I}_{\text{C}} &= 50 \text{ mAdc, V}_{\text{CE}} = 1.0 \text{ Vdc)} \\ \text{(I}_{\text{C}} &= 250 \text{ mAdc, V}_{\text{CE}} = 1.0 \text{ Vdc)} \end{aligned} $	h _{FE}	80 50	_ 250	-
Collector – Emitter Saturation Voltage (I _C = 250 mAdc, I _B = 10 mAdc)	V _{CE(sat)}	_	0.5	Vdc
Base – Emitter On Voltage (I _C = 250 mAdc, V _{CE} = 1.0 Vdc)	V _{BE(on)}	_	1.2	Vdc
SMALL-SIGNAL CHARACTERISTICS		•	•	
Collector–Base Capacitance ($V_{CB} = 10 \text{ Vdc}, I_E = 0, f = 1.0 \text{ MHz}$)	C _{cb}	_	30	pF
Small–Signal Current Gain (I _C = 200 mAdc, V _{CE} = 5.0 Vdc, f = 20 MHz)	h _{fe}	2.5	25	-

^{1.} Pulse Test: Pulse Width \leq 300 μ s; Duty Cycle \leq 2.0%.

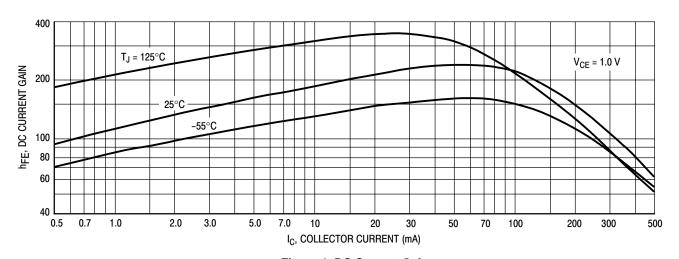


Figure 1. DC Current Gain

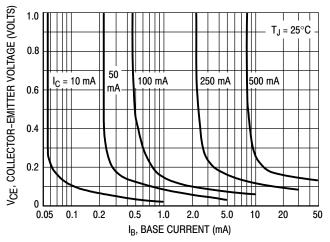


Figure 2. Collector Saturation Region

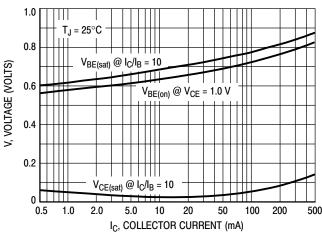


Figure 3. "On" Voltages

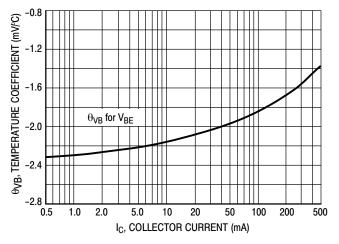


Figure 4. Base-Emitter Temperature Coefficient

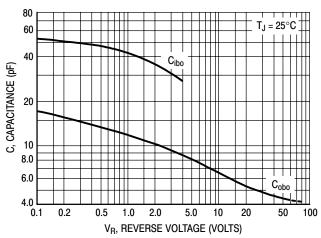


Figure 5. Capacitance

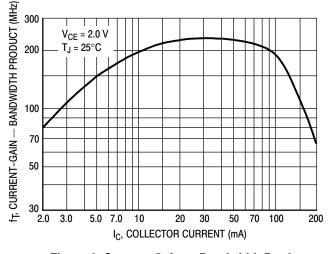


Figure 6. Current-Gain — Bandwidth Product

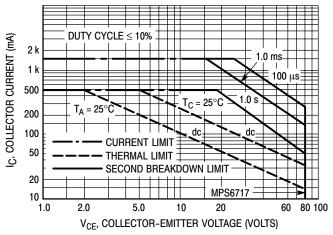
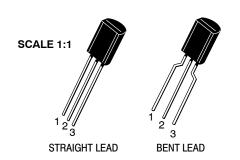


Figure 7. Active Region — Safe Operating Area

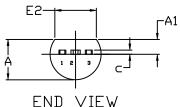


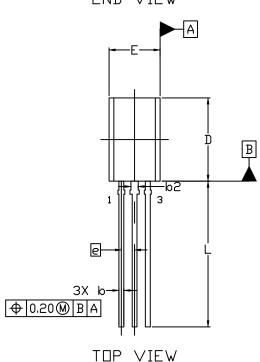


TO-92 (TO-226) 1 WATT CASE 29-10 ISSUE D

DATE 05 MAR 2021

STRAIGHT LEAD





NOTES:

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2009.
- CONTROLLING DIMENSION: MILLIMETERS
- 3. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH OR GATE PROTRUSIONS.
- 4. DIMENSION 6 AND 62 DOES NOT INCLUDE DAMBAR PROTRUSION. LEAD WIDTH INCLUDING PROTRUSION SHALL NOT EXCEED 0.20. DIMENSION 62 LOCATED ABOVE THE DAMBAR PORTION OF MIDDLE LEAD.

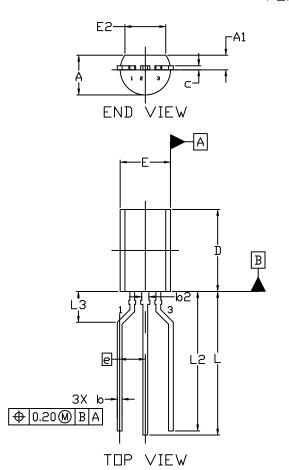
	MILLIMETERS						
DIM	MIN.	N□M.	MAX.				
Α	3.75	3.90	4.05				
A1	1.28	1.43	1.58				
b	0.38	0.465	0.55				
b2	0.62	0.70	0.78				
c	0.35	0.40	0.45				
D	7.85	8.00	8.15				
E	4.75	4.90	5.05				
E2	3.90						
е	1.27 BSC						
L	13.80 14.00 14.20						

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FORMED LEAD



NOTES:

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	MILLIMETERS					
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Ε	4.75	4.90	5.05			
E2	3.90					
e		2.50 BSC				
L	13.80	14.00	14.20			
L2	13.20	13.60	14.00			
L3	3.00 REF					

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CASE 29-10 ISSUE D

DATE 05 MAR 2021

2.	EMITTER BASE COLLECTOR		BASE EMITTER COLLECTOR		ANODE ANODE CATHODE		CATHODE CATHODE ANODE		DRAIN SOURCE GATE
	GATE	STYLE 7: PIN 1. 2. 3.	SOURCE DRAIN	STYLE 8: PIN 1. 2. 3.	DRAIN GATE	2.	BASE 1	2.	CATHODE GATE ANODE
2.	ANODE CATHODE & ANODE	PIN 1. 2.	MAIN TERMINAL 1	PIN 1. 2.	ANODE 1 GATE	2.	EMITTER	2.	ANODE 1 CATHODE ANODE 2
2.	ANODE GATE CATHODE	STYLE 17: PIN 1. 2. 3.	COLLECTOR BASE EMITTER		ANODE CATHODE NOT CONNECTED		GATE ANODE CATHODE	2.	NOT CONNECTED CATHODE ANODE
2.		2.	SOURCE GATE DRAIN		GATE SOURCE DRAIN	PIN 1. 2.	EMITTER	2.	MT 1
	V _{CC}			PIN 1. 2.		PIN 1. 2.	NOT CONNECTED ANODE CATHODE		
	GATE	STYLE 32: PIN 1. 2. 3.	BASE COLLECTOR EMITTER	2.	RETURN INPUT OUTPUT	PIN 1. 2.	INPUT GROUND LOGIC		

GENERIC MARKING DIAGRAM*



XXXX = Specific Device Code

A = Assembly Location

L = Wafer Lot

Y = Year

W = Work Week

■ = Pb-Free Package

(Note: Microdot may be in either location)

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

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